

#034 F/T:-; C:175S; T:D; S:+4+(150%); D:?: DF:N

This very strong conductor of 150% of normal (as against less than 50% to the north) coincides with a strong external polarization current.

#035 F/T:-; C:070S; T:B; S:-3; D:45M; DF:N

#036 F/T:-; C:012N; T:B; S:-3½; D:40M; DF:N

The above two responses are definite and arise from chargeable material contained within a host showing little to no contrast with the enclosing material.

LINE 700W NORTHERN SECTION

#037 F/T:888N-950N; C:920N; T:C/B; S:(R)-5; D:60M; DF:N

This substantial internal polarization response rises over 5 milligammas/gamma above strong external polarization current flows, which reach +5 milligammas/gamma at 850N. The H_N reaches a peak value of just under 110% at 900N, as against less than 85% to north and south of this anomaly. Thus, the host to the chargeable material shows a variation of conduction within it.

#038 F/T:1000N-1050N; C:1037N; T:C?; S:-2; D:50M?; DF:s

Unfortunately, this internal polarization anomaly showing a slow decay form (rare in this area) occurs on the edge of the array.